

View Online at <https://aerobasegroup.com/nsn/5961-01-581-2531>

**Inclosure Material:**

Glass

**End Application:**

Ca70608-00 (19156) , receiver-transmitter

**Mounting Facility Quantity:**

2

**Mounting Method:**

Unthreaded hole

**Semiconductor Material:**

Silicon

**Voltage Rating In Volts Per Characteristic:**

60.0 collector to base voltage, dc and 4.0 emitter to base voltage, dc and 60.0 breakdown voltage, collector to emitter, sustained

**Current Rating Per Characteristic:**

4.50 amperes collector current, dc

**Power Rating Per Characteristic:**

225.0 watts total power dissipation and 45.0 watts power output

**Product Name:**

Dwg: rf transistor; cage: 45 watts, 50 volts, pulsed avionics 960 - 1215 mhz; common base bipolar transistor

**Precious Material And Location:**

Thin-film metallization gold

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

Yes - demil/mli

**Fiig:**

A110a0